Diode Semiconductor Device - Page 1 of 1



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Inclosur	e Material:
Metal	
Overall L	_ength:
0.030 inc	hes
Termina	I Length:
1.000 inc	hes
Overall [Diameter:
0.420 inc	hes
Mountin	g Method:
Terminal	
Features	s Provided:
Hermetic	ally sealed case
Semicon	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
100.0 re	verse voltage, peak
Current	Rating Per Characteristic:
3.00 amp	peres forward current, average absolute
Maximur	m Operating Tempurature Per Measurement Point:
175.0 de	grees celsius ambient air
Termina	I Type And Quantity:
2 uninsul	ated wire lead
Shelf Lif	e:
N/a	
Unit Of M	Measure:
Demilita	rization:
No	
Fiig:	
A110a0	